

8 CHANNEL MULTIPLEXER/REGISTER WITH LATCHES (3-STATE)

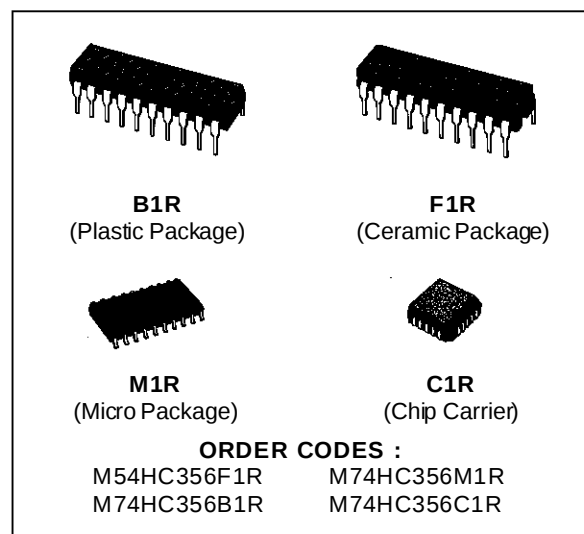
- HIGH SPEED
 $t_{PD} = 25 \text{ ns}$ (TYP.) AT $V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION
 $I_{CC} = 4 \mu\text{A}$ (MAX.) AT $T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (MIN.)
- OUTPUT DRIVE CAPABILITY
15 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
 $|I_{OH}| = I_{OL} = 6 \text{ mA}$ (MIN.)
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
 V_{CC} (OPR) = 2 V TO 6 V
- PIN AND FUNCTION COMPATIBLE WITH
54/74LS356

DESCRIPTION

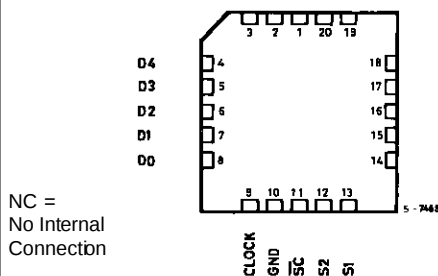
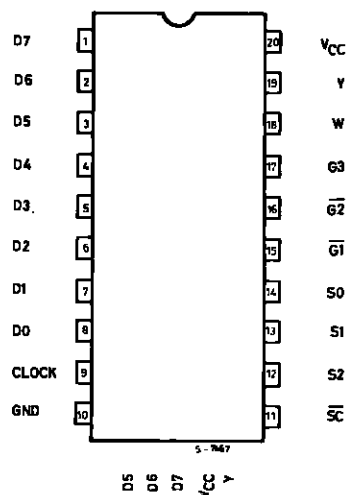
The M54/74HC356 is a high speed CMOS 8-CHANNEL MULTIPLEXER/REGISTER (3-State) fabricated in silicon gate C²MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low consumption.

This device contains an 8 channel digital multiplexer with an 8-bit input data register and a 3-bit address input register with 3-state outputs. The one of eight input data will be provided on the Y output pin (non-inverted output) and W output pin (inverted output) is determined by the address data.

The information at the data inputs (D0 to D7) is stored in the 8-bit flip-flop at the positive going edge of clock input (CLOCK). The information at the address inputs (S0 to S2) is stored in the 3-bit latch at the negative pulse on SC input. These outputs are disabled to be high-impedance when input $\overline{G1}$ is held high, input $\overline{G2}$ is held high or input G3 is held low. This device is suitable for interfacing with bus lines in a bus organized system. The M54/74HC356 is similar in function to the M54/74HC354, which has an 8-bit latch as the data register instead of an 8-bit flip-flop. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

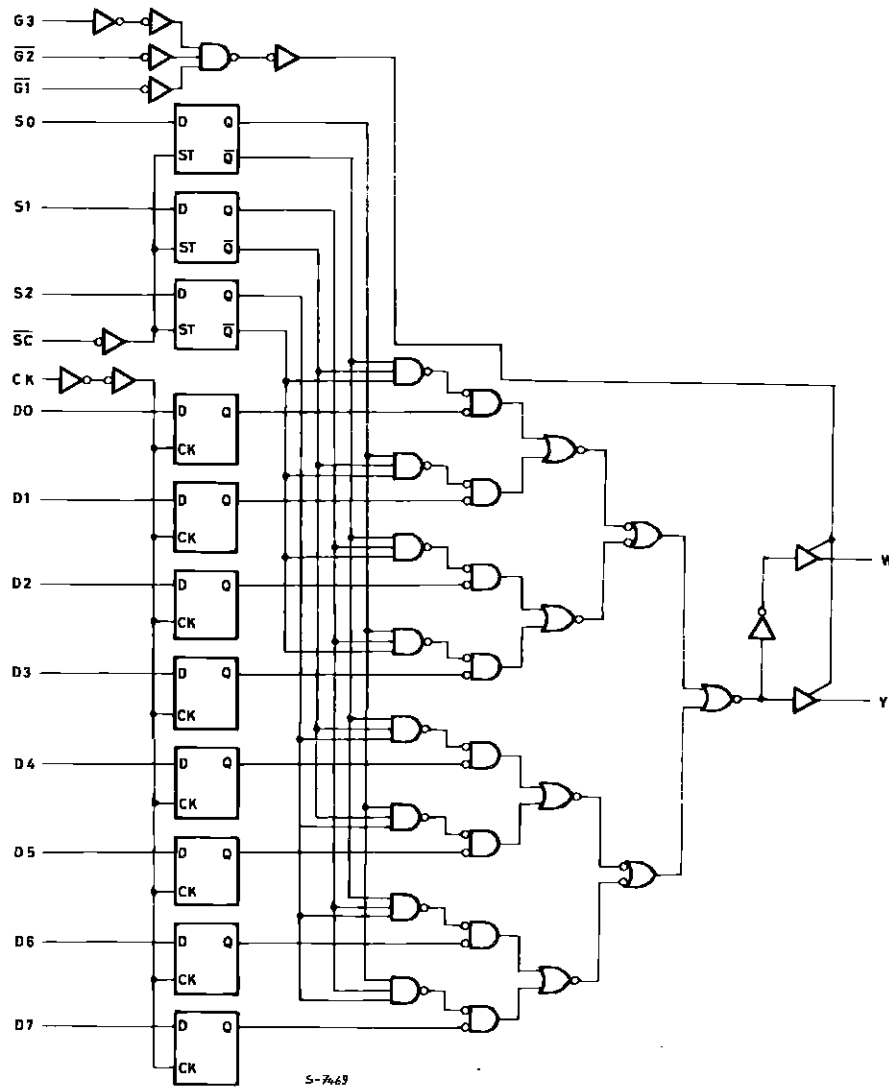


PIN CONNECTIONS (top view)



NC =
No Internal
Connection

LOGIC DIAGRAM

TRUTH TABLE OF INTERNAL
LATCH

INPUTS		OUTPUTS	
D	ST	Q	$\bar{Q}$
L	H	L	H
H	H	H	L
X	L	Qn	$\bar{Q}n$

X: DON'T CARE

Qn: DATA STORED AT THE TRAILING
EDGE OF THE MOST RECENT ST
PULSETRUTH TABLE OF INTERNAL
LATCH (FLIP FLOP)

D	CK	Q
L		L
H		H
X		Qn

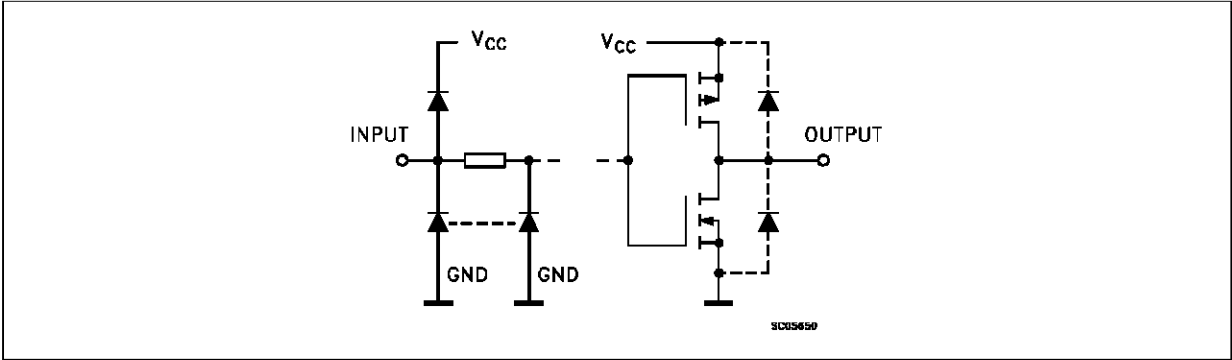
X: DON'T CARE
Qn: NO CHANGE

TRUTH TABLE

INPUTS								
SELECT *			CLOCK	OUTPUT ENABLES			W	Y
S2	S1	S0		G1	G2	G3		
X	X	X	X	H	X	X	Z	Z
X	X	X	X	X	H	X	Z	Z
X	X	X	X	X	X	L	Z	Z
L	L	L		L	L	H	$\overline{D0}$	D0
L	L	L		L	L	H	$\overline{D0n}$	D0n
L	L	H		L	L	H	$\overline{D1}$	D1
L	L	H		L	L	H	$\overline{D1n}$	D1n
L	H	L		L	L	H	$\overline{D2}$	D2
L	H	L		L	L	H	$\overline{D2n}$	D2n
L	H	H		L	L	H	$\overline{D3}$	D3
L	H	H		L	L	H	$\overline{D3n}$	D3n
H	L	L		L	L	H	$\overline{D4}$	D4
H	L	L		L	L	H	$\overline{D4n}$	D4n
H	L	H		L	L	H	$\overline{D5}$	D5
H	L	H		L	L	H	$\overline{D5n}$	D5n
H	H	L		L	L	H	$\overline{D6}$	D6
H	H	L		L	L	H	$\overline{D6n}$	D6n
H	H	H		L	L	H	$\overline{D7}$	D7
H	H	H		L	L	H	$\overline{D7n}$	D7n

X: DON'T CARE Z: HIGH IMPEDANCE *: This column shows the input adress setup with SC LOW.
D1 D7: The level of steady state inputs at input D1 through D7, respectively, at the time of the LOW to HIGH transition of the clock.

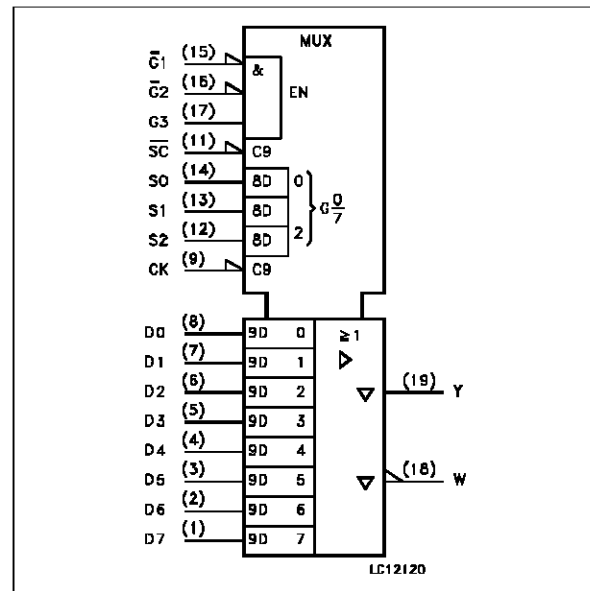
INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
8, 7,, 6, 5, 4, 3, 2, 1	D0 to D7	Data Inputs
9	CLOCK	Clock Input (LOW to HIGH, Edge-triggered)
11	$\overline{SC}$	Latch Enable Input (Active LOW)
14, 13, 12	S0, S1, S2	Select Inputs
15, 16	$\overline{G1}, \overline{G2}$	Output Enable Inputs (Active LOW)
17	G3	Output Enable Inputs (Active HIGH)
18	W	3 State Multiplexer Output (Active LOW)
19	Y	3 State Multiplexer Output (Active HIGH)
10	GND	Ground (0V)
20	V _{CC}	Positive Supply Voltage

IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7	V
V _I	DC Input Voltage	-0.5 to V _{CC} + 0.5	V
V _O	DC Output Voltage	-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	± 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
I _O	DC Output Source Sink Current Per Output Pin	± 35	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	± 70	mA
P _D	Power Dissipation	500 (*)	mW
T _{stg}	Storage Temperature	-65 to +150	°C
T _L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: ± 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V _{CC}	Supply Voltage		2 to 6	V
V _I	Input Voltage		0 to V _{CC}	V
V _O	Output Voltage		0 to V _{CC}	V
T _{op}	Operating Temperature: M54HC Series M74HC Series		-55 to +125 -40 to +85	°C °C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 2 V	0 to 1000	ns
		V _{CC} = 4.5 V	0 to 500	
		V _{CC} = 6 V	0 to 400	

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions		Value						Unit			
		V _{CC} (V)		T _A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC				
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.		
V _{IH}	High Level Input Voltage	2.0		1.5			1.5		1.5		V		
		4.5		3.15			3.15		3.15				
		6.0		4.2			4.2		4.2				
V _{IL}	Low Level Input Voltage	2.0				0.5		0.5		0.5	V		
		4.5				1.35		1.35		1.35			
		6.0				1.8		1.8		1.8			
V _{OH}	High Level Output Voltage	2.0	V _I = V _{IH} or V _{IL}	I _O =-20 μA	1.9	2.0		1.9		1.9		V	
		4.5			4.4	4.5		4.4		4.4			
		6.0			5.9	6.0		5.9		5.9			
		4.5		I _O =-6.0 mA	4.18	4.31		4.13		4.10			
		6.0			I _O =-7.8 mA	5.68	5.8		5.63		5.60		
V _{OL}	Low Level Output Voltage	2.0	V _I = V _{IH} or V _{IL}	I _O = 20 μA			0.0	0.1		0.1		0.1	V
		4.5				0.0	0.1		0.1		0.1		
		6.0				0.0	0.1		0.1		0.1		
		4.5		I _O = 6.0 mA		0.17	0.26		0.33		0.40		
		6.0			I _O = 7.8 mA		0.18	0.26		0.33		0.40	
I _I	Input Leakage Current	6.0	V _I = V _{CC} or GND				±0.1		±1		±1	μA	
I _{OZ}	3 State Output Off State Current	6.0	V _I = V _{IH} or V _{IL} V _O = V _{CC} or GND			±0.5		±5.0		±10	μA		
I _{CC}	Quiescent Supply Current	6.0	V _I = V _{CC} or GND			4		40		80	μA		

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input t_r = t_f = 6 ns)

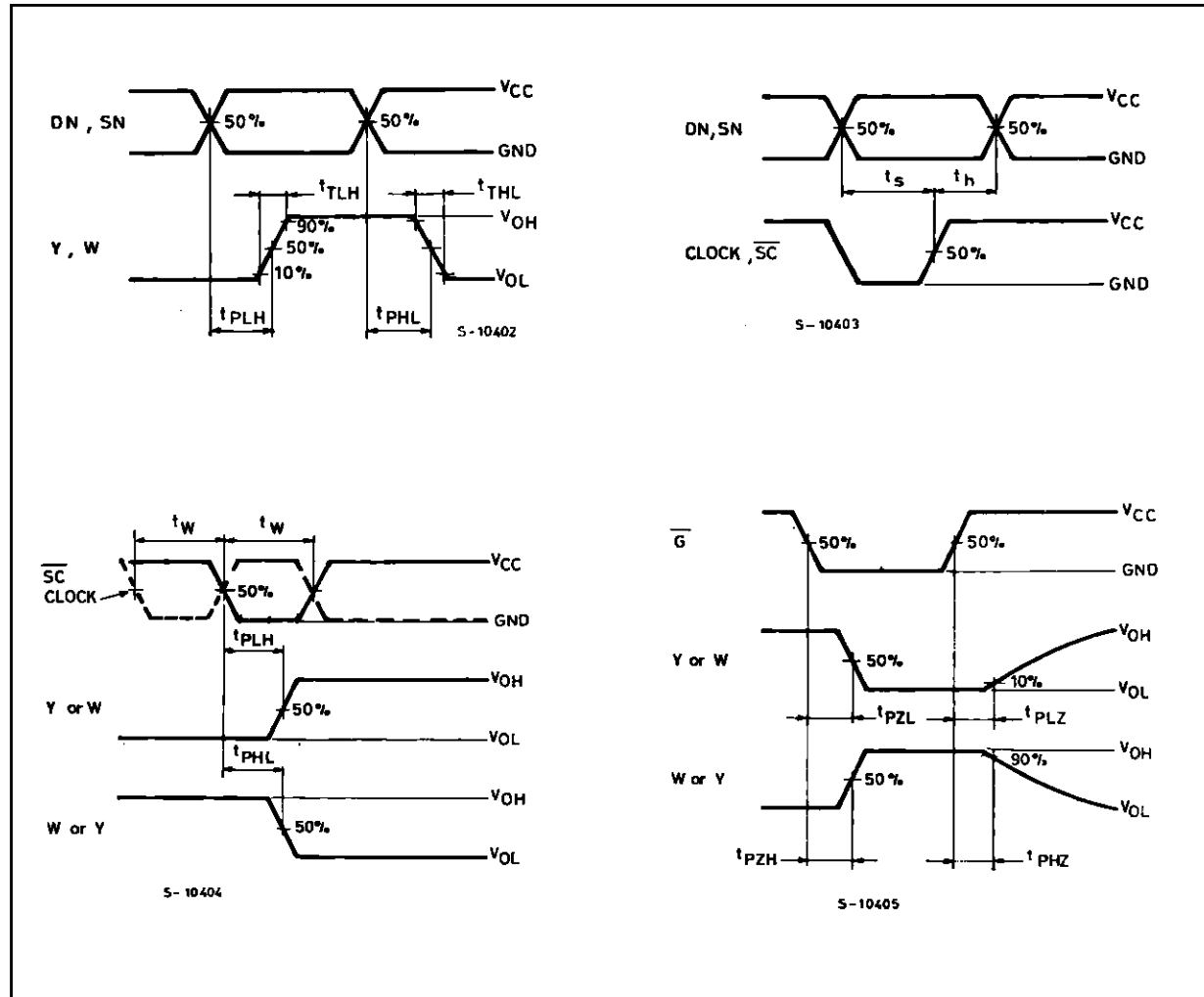
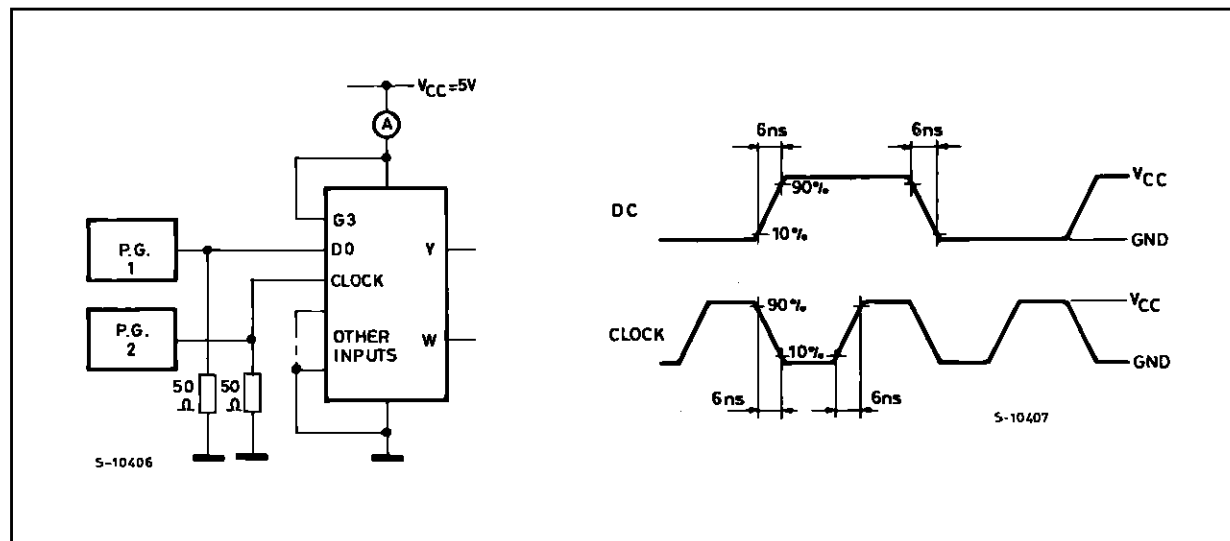
Symbol	Parameter	Test Conditions			Value						Unit	
		V _{CC} (V)	C _L (pF)		T _A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t _{TLH} t _{THL}	Output Transition Time	2.0	50			25	60		75		90	ns
		4.5				7	12		15		18	
		6.0				6	10		13		15	
t _{PLH} t _{PHL}	Propagation Delay Time (CLOCK - Y, W)	2.0	50			99	240		300		360	ns
		4.5				28	48		60		72	
		6.0				22	41		51		61	
		2.0	150			117	280		350		420	ns
		4.5				33	56		70		84	
		6.0				26	48		60		71	

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Symbol	Parameter	Test Conditions			Value						Unit	
		V _{CC} (V)	C _L (pF)		T _A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
					Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t _{PLH} t _{PHL}	Propagation Delay Time (Sn - Y, W)	2.0	50			111	260		325		390	ns
		4.5				32	52		65		78	
		6.0				24	44		55		66	
		2.0	150			128	300		375		450	ns
		4.5				37	60		75		90	
		6.0				28	51		64		77	
t _{PLH} t _{PHL}	Propagation Delay Time (SC - Y, W)	2.0	50			115	270		340		405	ns
		4.5				33	54		68		81	
		6.0				25	46		58		69	
		2.0	150			132	310		390		465	ns
		4.5				38	62		78		93	
		6.0				29	53		66		79	
t _{PZL} t _{PZH}	3 State Output Enable Time	2.0	50	R _L = 1 KΩ		48	125		155		190	ns
		4.5				14	25		31		38	
		6.0				11	21		26		32	
		2.0	150	R _L = 1 KΩ		65	165		205		250	ns
		4.5				19	33		41		50	
		6.0				15	28		35		43	
t _{PLZ} t _{PHZ}	3 State Output Disable Time	2.0	50	R _L = 1 KΩ		43	155		195		235	ns
		4.5				18	31		39		47	
		6.0				16	26		33		40	
f _{MAX}	Maximum Clock Frequency	2.0	50		6.2	20		5		4.2		ns
		4.5			31	80		25		21		
		6.0			37	82		30		25		
t _{W(L)} t _{W(H)}	Minimum Pulse Width (CLOCK)	2.0	50			25	75		95		110	ns
		4.5				6	15		19		22	
		6.0				6	13		16		19	
t _{W(L)}	Minimum Pulse Width (SC)	2.0	50			13	75		95		110	ns
		4.5				6	15		19		22	
		6.0				6	13		16		19	
t _s	Minimum Set-up Time (Dn)	2.0	50			21	50		65		75	ns
		4.5				4	10		113		15	
		6.0				3	9		11		13	
t _s	Minimum Set-up Time (Sn)	2.0	50			9	50		65		75	ns
		4.5				2	10		13		15	
		6.0				2	9		11		13	
t _h	Minimum Hold Time (Dn) (Sn)	2.0	50				5		5		5	ns
		4.5					5		5		5	
		6.0					5		5		5	
C _{IN}	Input Capacitance					5	10		10		10	pF
C _{PD} (*)	Power Dissipation Capacitance					59						pF

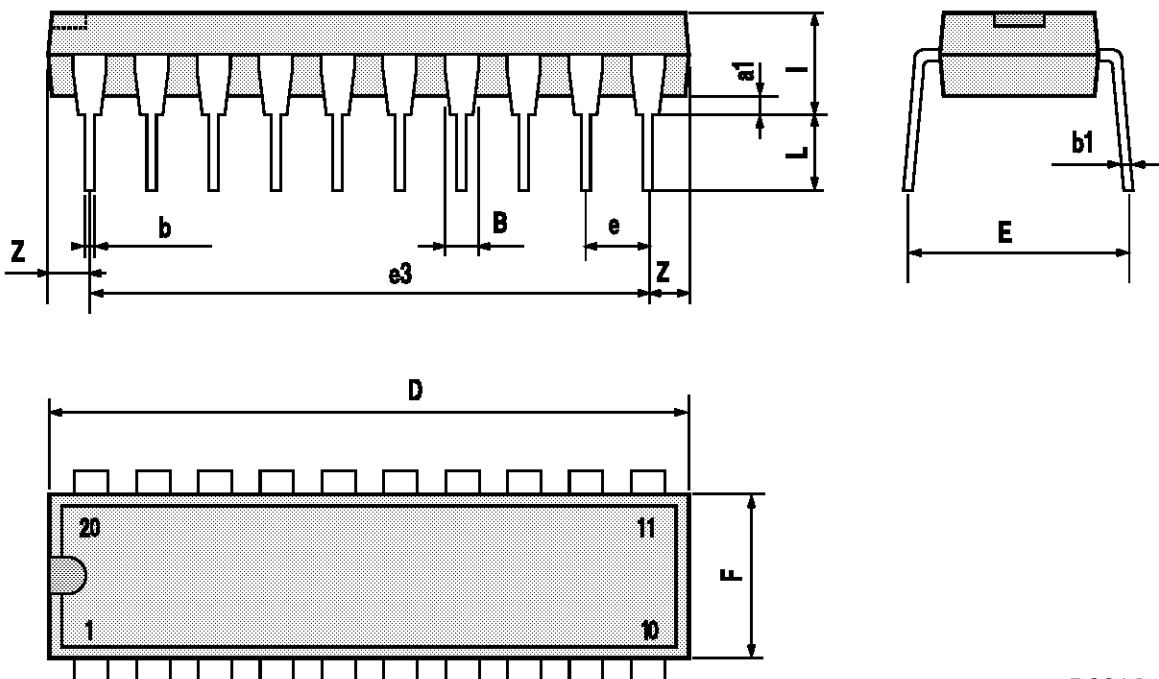
(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

SWITCHING CHARACTERISTICS TEST WAVEFORM

TEST CIRCUIT WAVEFORM I_{CC} (Opr.)

Plastic DIP20 (0.25) MECHANICAL DATA

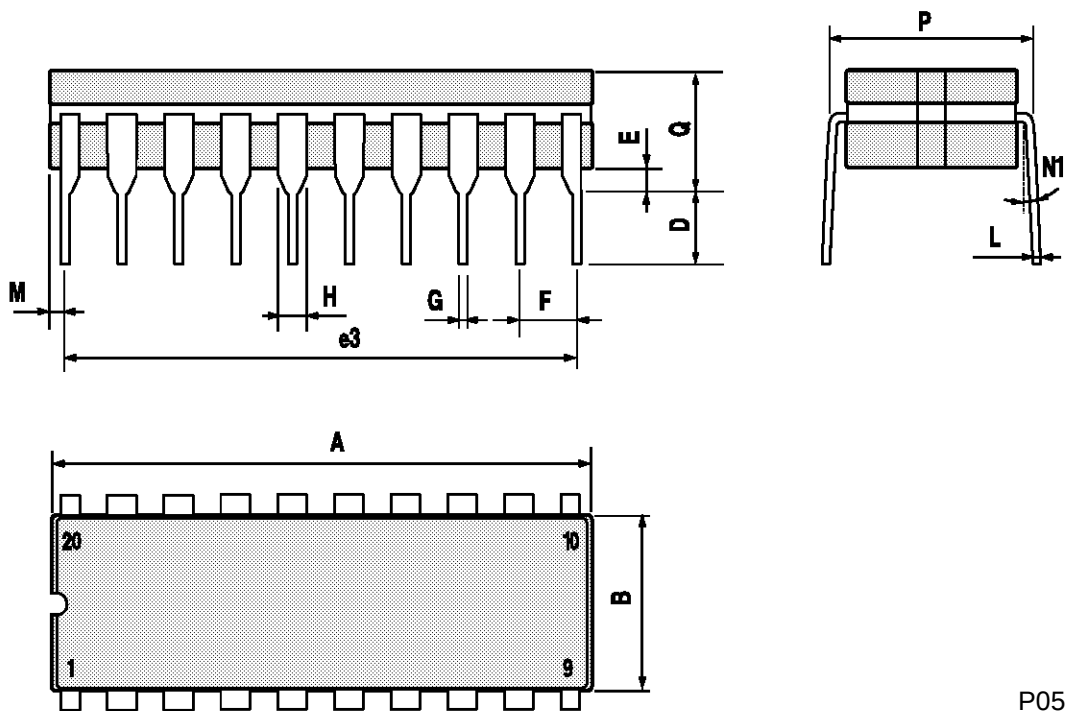
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.254			0.010		
B	1.39		1.65	0.055		0.065
b		0.45			0.018	
b1		0.25			0.010	
D			25.4			1.000
E		8.5			0.335	
e		2.54			0.100	
e3		22.86			0.900	
F			7.1			0.280
I			3.93			0.155
L		3.3			0.130	
Z			1.34			0.053



P001J

Ceramic DIP20 MECHANICAL DATA

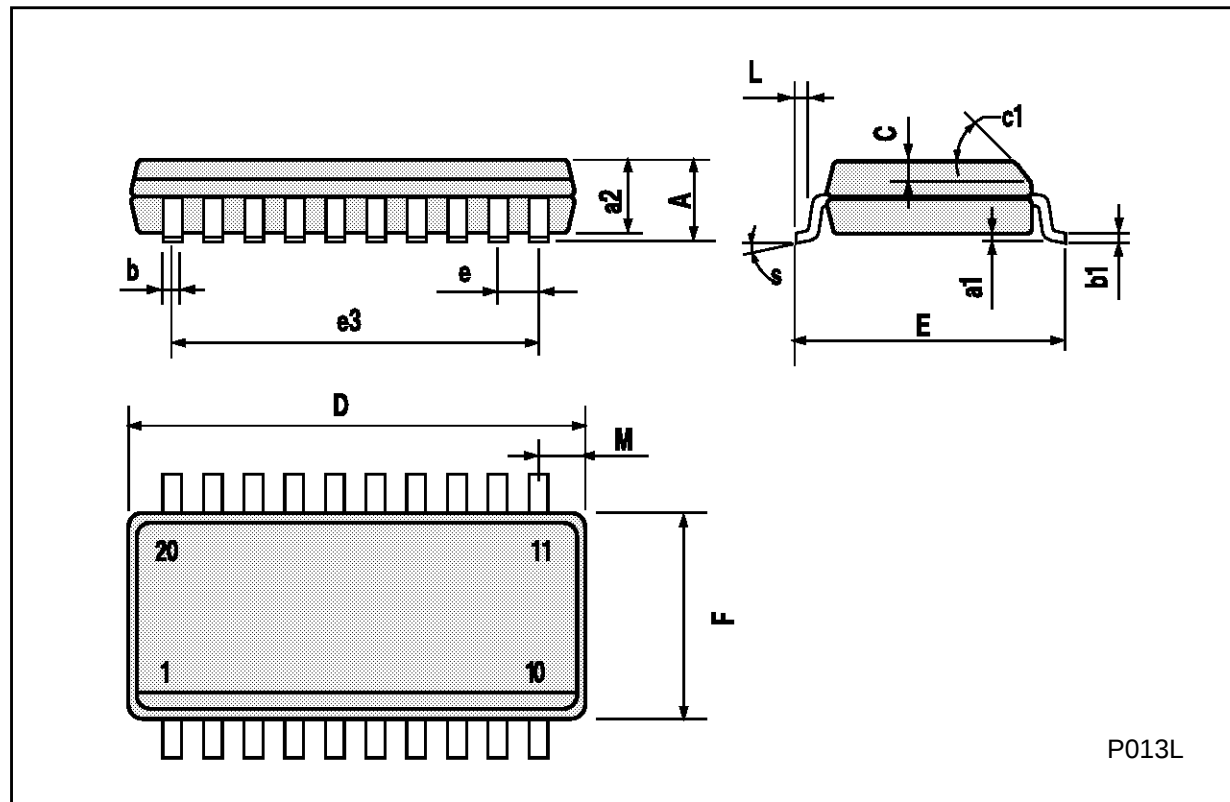
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			25			0.984
B			7.8			0.307
D		3.3			0.130	
E	0.5		1.78	0.020		0.070
e3		22.86			0.900	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
I	1.27		1.52	0.050		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N1	4° (min.), 15° (max.)					
P	7.9		8.13	0.311		0.320
Q			5.71			0.225



P057H

SO20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			2.65			0.104
a1	0.10		0.20	0.004		0.007
a2			2.45			0.096
b	0.35		0.49	0.013		0.019
b1	0.23		0.32	0.009		0.012
C		0.50			0.020	
c1	45° (typ.)					
D	12.60		13.00	0.496		0.512
E	10.00		10.65	0.393		0.419
e		1.27			0.050	
e3		11.43			0.450	
F	7.40		7.60	0.291		0.299
L	0.50		1.27	0.19		0.050
M			0.75			0.029
S	8° (max.)					



PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.